ART2K0FE; ART2K0FES; ART2K0FEG Power LDMOS transistor A Rev. 5 – 8 July 2022 Pro

AMPLEON Product data sheet

Product profile 1.

1.1 General description

Based on Advanced Rugged Technology (ART), this 2000 W LDMOS RF power transistor has been designed to cover a wide range of applications for ISM, broadcast and communications. The unmatched transistor has a frequency range of 1 MHz to 400 MHz.

Table 1.	Application	information

Test signal	f	V _{DS}	PL	Gp	η _D
	(MHz)	(V)	(W)	(dB)	(%)
CW	41.0	65	1600	29.0	79
CW	60.0	65	1750	26.8	80
CW pulsed [1]	64.0	63	2180	27.5	78
CW [2]	87.5 to 108	60	1650	26	83.5
DVB-T [3][4]	170 to 240	63	250	21	48
CW	352	65	1500	19	74

[1] $t_p = 10 \ \mu s; \ \delta = 10 \ \%.$

[2] Center band performance numbers across the indicated frequency range.

[3] Typical performance numbers across the indicated frequency range.

[4] Symmetric Ultra Wideband Doherty.

1.2 Features and benefits

- High breakdown voltage enables class E operation up to V_{DS} = 53 V
- Qualified up to a maximum of V_{DS} = 65 V
- Characterized from 30 V to 65 V to support a wide range of applications
- Integrated dual sided ESD protection enables class C operation and complete switch off of the transistor
- Excellent ruggedness with no device degradation
- High efficiency
- Excellent thermal stability
- Designed for broadband operation
- For RoHS compliance see the product details on the Ampleon website

1.3 Applications

- Industrial, scientific and medical applications
 - Plasma generators
 - MRI systems
 - CO₂ lasers
 - Particle accelerators
- Broadcast
 - FM radio
 - VHF TV
- Communications
 - Non cellular communications
 - UHF radar

2. Pinning information

Description	Simplified outline	Graphic symbol
E (SOT539AN)		
drain1		1
drain2		l l
gate1		
gate2	3 4	4 - 1 - 5
source	[1]	
		2 sym117
ES (SOT539BN)		
drain1		1
drain2		نے ا
gate1	5	3 — ⊨
gate2	3 4	4 - - 5
source	[1]	
		2
EG (SOT1248C)		sym117
drain1		1
drain2		
gate1	5	3-4
gate2		4
source	[1]	
		2
	Image: Solution of the system of the syst	E (SOT539AN)drain1drain2gate1 $1 + 2 + \frac{1}{2} + \frac{1}{2} + \frac{1}{3} + \frac{1}{$

[1] Connected to flange.

3. Ordering information

Table 3. Ordering information					
Package name	Orderable part number	12NC	Packing description	Min. orderable quantity (pieces)	
SOT539AN	ART2K0FEU	9349 602 80112	Tray; 20-fold; non-dry pack	60	
SOT539BN	ART2K0FESU	9349 605 38112	Tray; 20-fold; non-dry pack	60	
SOT1248C	ART2K0FEGJ	9349 605 37118	TR13; 100-fold; 56 mm; non-dry pack	100	

4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	I	Min	Max	Unit
V _{DS}	drain-source voltage	<u>1</u>	1] .	-	200	V
V _{GS}	gate-source voltage		-	-9	+13	V
T _{stg}	storage temperature		-	-65	+150	°C
Tj	junction temperature	[2]	-	225	°C

[1] Specified over lifetime at maximum operating temperature.

[2] Continuous use at maximum temperature will affect the reliability, for details refer to the online MTF calculator.

5. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Тур	Unit
R _{th(j-c)}	thermal resistance from junction to case	T _j = 95 °C	0.077	K/W
Z _{th(j-c)}	transient thermal impedance from junction to case	$T_j = 95 \text{ °C}; t_p = 100 \mu\text{s};$ $\delta = 10 \%$	0.018	K/W

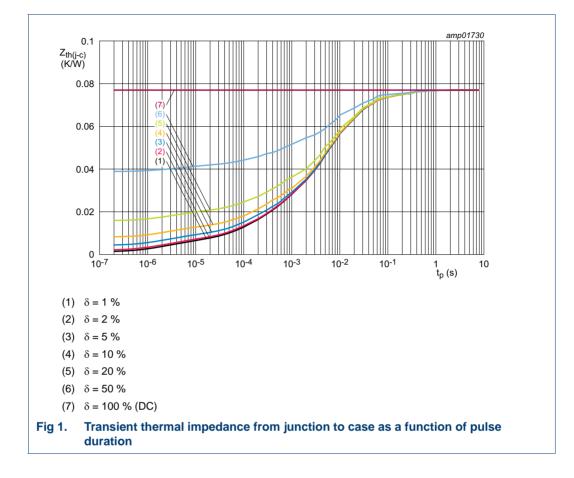
[1] T_j is the junction temperature.

[2] R_{th(j-c)} is measured under RF conditions.

[3] See Figure 1.

ART2K0FE(S)(G)

Power LDMOS transistor



6. Characteristics

Table 6. DC characteristics

 $T_i = 25 \ ^{\circ}C$; per section unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{(BR)DSS}	drain-source breakdown voltage	$V_{GS} = 0 V; I_D = 5.5 mA$	203	208	-	V
V _{GS(th)}	gate-source threshold voltage	V _{DS} = 20 V; I _D = 550 mA	1.5	2.1	2.5	V
I _{DSS}	drain leakage current	$V_{GS} = 0 V; V_{DS} = 65 V$	-	-	2.8	μA
I _{DSX}	drain cut-off current	$\label{eq:VGS} \begin{array}{l} V_{GS} = V_{GS(th)} + 3.75 \; V; \\ V_{DS} = 20 \; V \end{array}$	-	77	-	A
I _{GSS}	gate leakage current	V _{GS} = 13 V; V _{DS} = 0 V	-	-	280	nA
R _{DS(on)}	drain-source on-state resistance	$V_{GS} = V_{GS(th)} + 3.75 V;$ I _D = 19.25 A	-	0.100	-	Ω

Table 7.AC characteristics

 $T_j = 25$ °C; per section unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
C _{rs}	feedback capacitance	$V_{GS} = 0 V; V_{DS} = 65 V; f = 1 MHz$	-	1.73	-	pF
C _{iss}	input capacitance	V _{GS} = 0 V; V _{DS} = 65 V; f = 1 MHz	-	610	-	pF
C _{oss}	output capacitance	V _{GS} = 0 V; V _{DS} = 65 V; f = 1 MHz	-	181	-	pF

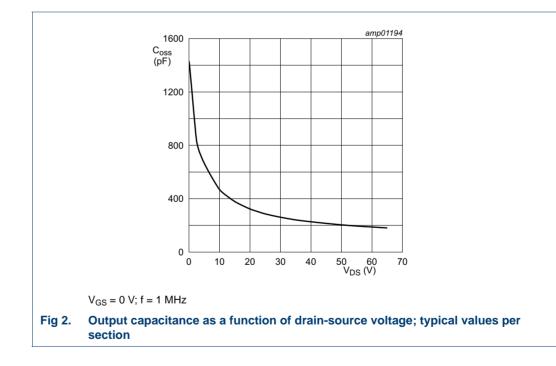


Table 8. RF characteristics

Test signal: pulsed RF; $t_p = 100 \ \mu s$; $\delta = 5 \ \%$; $f = 108 \ MHz$; RF performance at $V_{DS} = 65 \ V$; $I_{Dq} = 50 \ mA$ per section; $T_{case} = 25 \ ^{\circ}C$; unless otherwise specified; in a class-AB production test circuit.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Gp	power gain	P _L = 2000 W	27.0	28.4	-	dB
RL _{in}	input return loss	P _L = 2000 W	-	-13.9	-	dB
η _D	drain efficiency	P _L = 2000 W	69.0	72.1	-	%

7. Test information

7.1 Ruggedness in class-AB operation

The ART2K0FE, ART2K0FES and ART2K0FEG are capable of withstanding a load mismatch corresponding to VSWR \geq 65 : 1 through all phases under the following conditions: V_{DS} = 65 V; I_{Dq} = 100 mA per section; P_L = 2000 W pulsed; t_p = 100 µs; δ = 10 %; f = 108 MHz.

7.2 Impedance information

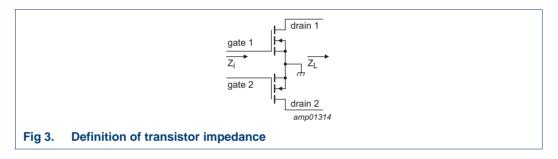


Table 9. Typical push-pull impedance

Simulated Z_i and Z_L device impedance; impedance info at $V_{DS} = 65$ V and $P_L = 2000$ W.

f	Z _i	ZL
(MHz)	(Ω)	(Ω)
108	2.4 – j8.7	3.8 + j1.0

7.3 Test circuit

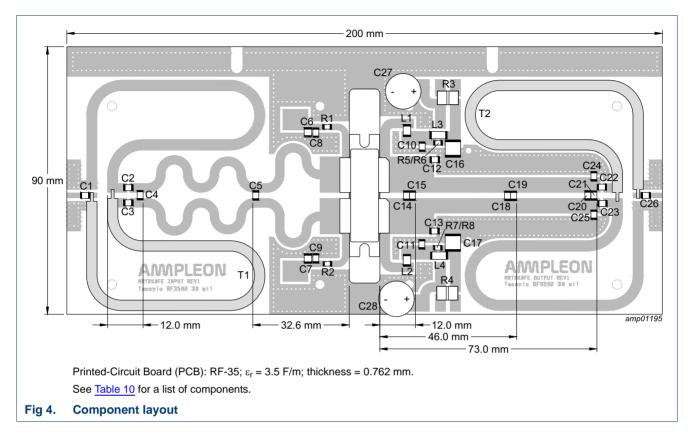


Table 10. List of components

For test circuit see Figure 4.

Component	Description	Value	Remarks
C1, C26	multilayer ceramic chip capacitor	470 pF [1]	
C2, C3	multilayer ceramic chip capacitor	68 pF [1]	
C4	multilayer ceramic chip capacitor	43 pF [1]	
C5	multilayer ceramic chip capacitor	240 pF [1]	
C6, C7	multilayer ceramic chip capacitor	4.7 μF, 50 V	Murata: GRM32ER71H475KA88L
C8, C9, C10, C11	multilayer ceramic chip capacitor	820 pF [1]	
C12, C13	multilayer ceramic chip capacitor	180 pF [1]	
C14, C15	multilayer ceramic chip capacitor	39 pF [1]	
C16, C17	multilayer ceramic chip capacitor	4.7 μF, 100 V	TDK: C5750X7R2A475KT/A
C18, C19	multilayer ceramic chip capacitor	56 pF [1]	
C20, C21	multilayer ceramic chip capacitor	51 pF [1]	
C22, C23	multilayer ceramic chip capacitor	120 pF [1]	
C24, C25	multilayer ceramic chip capacitor	20 pF [1]	
C27, C28	electrolytic capacitor	2200 μF, 100 V	
L1, L2	air inductor	47 nH	Coilcraft: 1515SQ-47N
L3, L4	air inductor	82 nH	Coilcraft: 1515SQ-82N
R1, R2	resistor	4.7 kΩ	SMD 1206

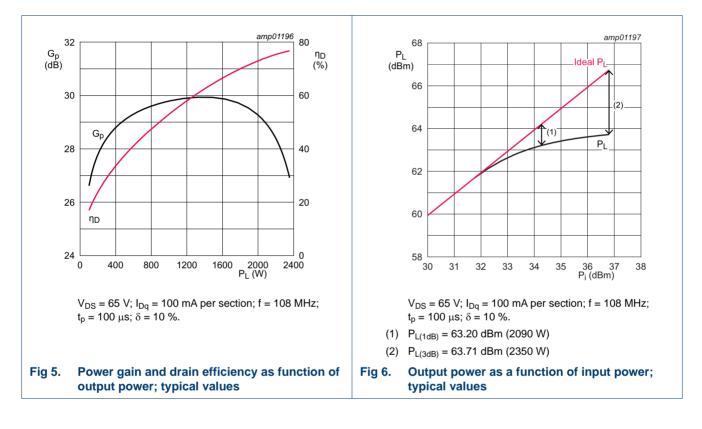
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Table 10. List of components ... continued

For test circuit see	Figure 4.
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Component	Description	Value	Remarks
R3, R4	resistor	0.01 Ω	Vishay: WSHP2818
R5, R6, R7, R8	resistor	9.1 Ω	SMD 1206
T1, T2	semi rigid coax	50 Ω, 160 mm	EZ141-AL-TP/M17

[1] American Technical Ceramics type 100B or capacitor of same quality.

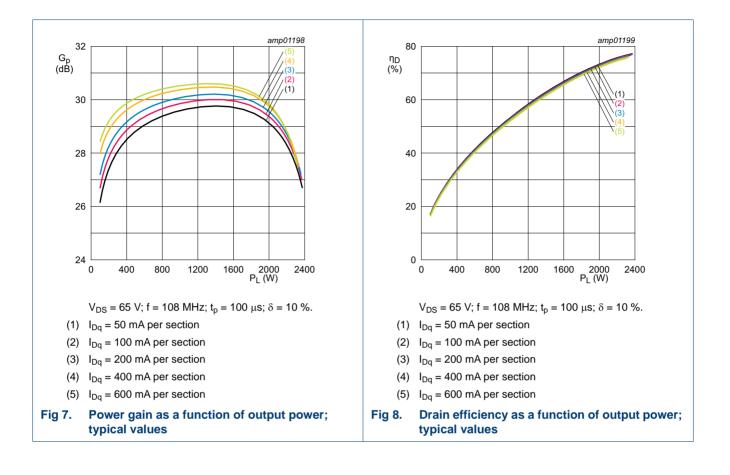


7.4 Graphical data

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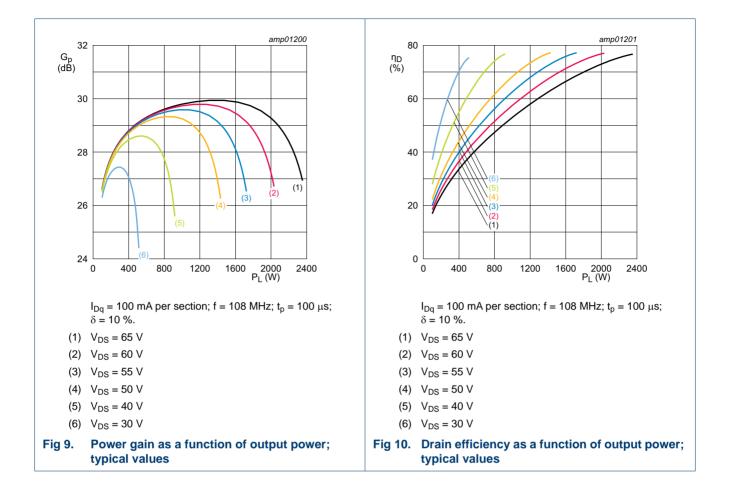
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8. Package outline

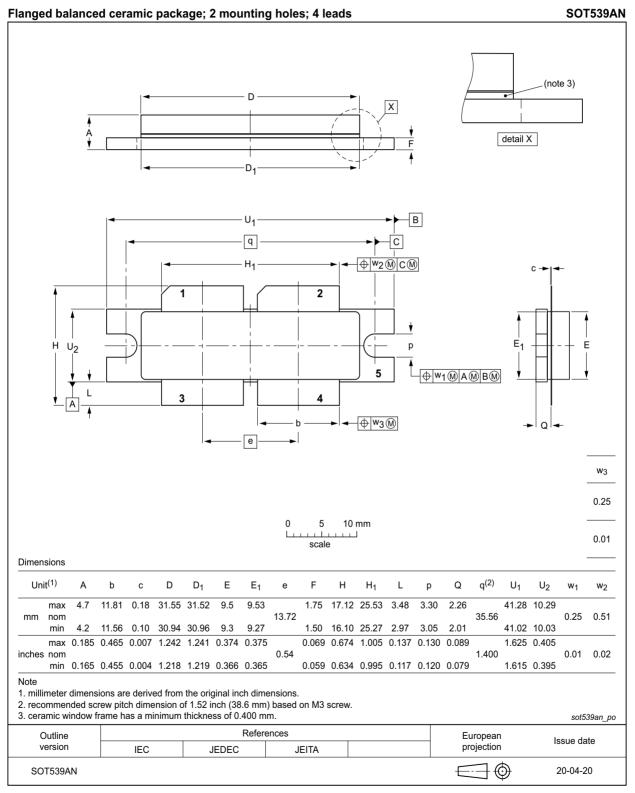


Fig 11. Package outline SOT539AN

ART2K0FE_2K0FES_2K0FEG

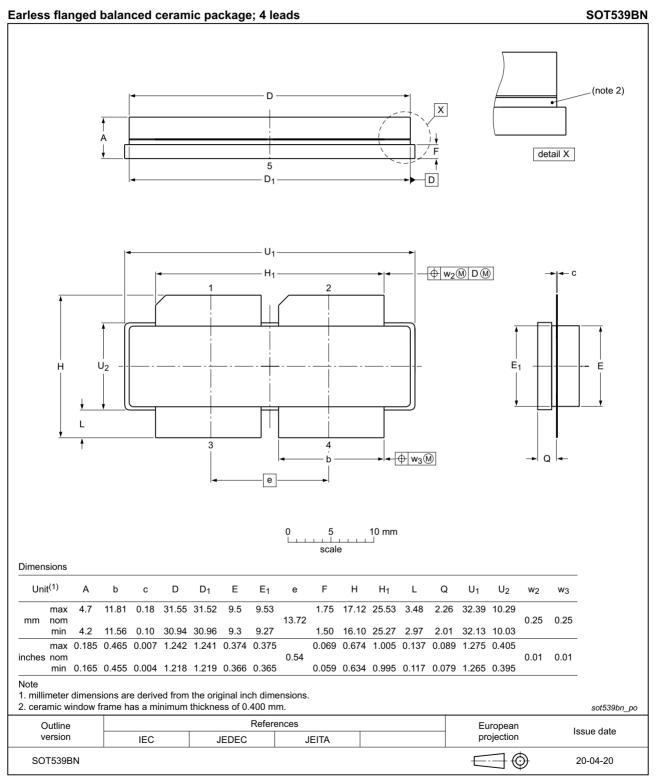


Fig 12. Package outline SOT539BN

ART2K0FE(S)(G)
Power LDMOS transistor

SOT1248C

Earless flanged LDMOST ceramic package; 4 leads

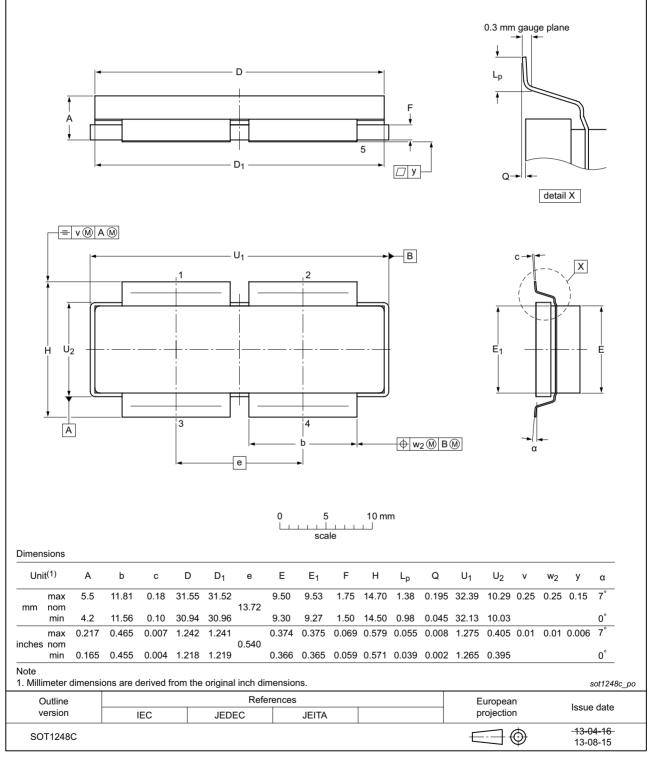


Fig 13. Package outline SOT1248C

9. Handling information

CAUTION



This device is sensitive to ElectroStatic Discharge (ESD). Observe precautions for handling electrostatic sensitive devices.

Such precautions are described in the ANSI/ESD S20.20, IEC/ST 61340-5, JESD625-A or equivalent standards.

Table 11.ESD sensitivity

ESD model	Class
Charged Device Model (CDM); According to ANSI/ESDA/JEDEC standard JS-002	C2A [1]
Human Body Model (HBM); According to ANSI/ESDA/JEDEC standard JS-001	2 [2]

[1] CDM classification C2A is granted to any part that passes after exposure to an ESD pulse of 500 V.

[2] HBM classification 2 is granted to any part that passes after exposure to an ESD pulse of 2000 V.

10. Abbreviations

Table 12. Abbreviations			
Acronym	Description		
CW	Continuous Wave		
DVB-T	Digital Video Broadcast - Terrestrial		
ESD	ElectroStatic Discharge		
FM	Frequency Modulation		
ISM	Industrial, Scientific and Medical		
LDMOS	Laterally Diffused Metal-Oxide Semiconductor		
MRI	Magnetic Resonance Imaging		
MTF	Median Time to Failure		
RoHS	Restriction of Hazardous Substances		
SMD	Surface Mounted Device		
UHF	Ultra High Frequency		
VHF	Very High Frequency		
VSWR	Voltage Standing Wave Ratio		

ART2K0FE_2K0FES_2K0FEG

11. Revision history

Table 13. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
ART2K0FE_2K0FES_2K0FEG v.5	20220708	Product data sheet	-	ART2K0FE_2K0FES_2K0FEG v.4
Modifications:	• Table 4 or	page 3: changed valu	ies gate-source v	oltage
	• <u>Table 6 or</u>	<u>page 5</u> : changed valu	le gate-source vo	ltage
ART2K0FE_2K0FES_2K0FEG v.4	20220322	Product data sheet	-	ART2K0FE v.3
ART2K0FE v.3	20210618	Product data sheet	-	ART2K0FE v.2
ART2K0FE v.2	20200508	Product data sheet	-	ART2K0FE v.1
ART2K0FE v.1	20200114	Objective data sheet	-	-

12. Legal information

12.1 Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
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[2] The term 'short data sheet' is explained in section "Definitions".

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Power LDMOS transistor

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